

Name of the Lab :Electronics laboratory

EC8311 (ODD Semester)

Regulation: R2017

Dept: EEE/III Sem

LIST OF EXPERIMENTS

EC8311-Electronics Laboratory

1. Characteristics of Semiconductor diode and Zener diode
2. Characteristics of a NPN Transistor under common emitter, common collector and common base configurations
3. Characteristics of JFET and draw the equivalent circuit
4. Characteristics of UJT and generation of saw tooth waveforms
5. Design and Frequency response characteristics of a Common Emitter amplifier
6. Characteristics of photo diode & photo transistor, Study of light activated relay circuit
7. Design and testing of RC phase shift and LC oscillators
8. Single Phase half-wave and full wave rectifiers with inductive and capacitive filters
9. Differential amplifiers using FET
10. Study of CRO for frequency and phase measurements.
11. Realization of passive filters.

Content Beyond the Syllabus

EC8311-Electronics Laboratory

1. Characteristics of Light Emitting Diode.
2. Study of Digital Storage Oscilloscope.
3. Design and testing of voltage feedback amplifier.